

Cascadable Amplifier 10 to 200 MHz

Rev. V4

Features

• HIGH REVERSE ISOLATION: >32 dB (TYP.)

VERY LOW NOISE: 2.0 dB (TYP.)

HIGH GAIN: 27.3 dB (TYP.)

• HIGH EFFICIENCY: 29 mA AT 15 VOLTS (TYP.)

Description

The A80-1 RF amplifier is a discrete hybrid design, which uses thin film manufacturing processes for accurate performance and high reliability.

The 2 stage silicon bipolar feedback amplifier design displays impressive performance over a broadband frequency range. An isolation transformer is used in the feedback loop, with the benefit of high reverse isolation.

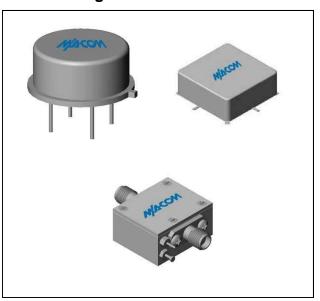
Both TO-8 and Surface Mount packages are hermetically sealed, and MIL-STD-883 environmental screening is available.

Ordering Information

Part Number	Package		
A80-1	TO-8		
SMA80-1	Surface Mount		
MAAM-007844-0CA801	SMA Connectorized **		

^{**} The connectorized version is not RoHs compliant.

Product Image



Electrical Specifications: $Z_0 = 50\Omega$, $V_{CC} = +15 V_{DC}$

Parameter	Units	Typical	Guaranteed	
Farameter		25°C	0º to 50ºC	-54º to +85ºC*
Frequency	MHz	5-200	10-200	10-200
Small Signal Gain (min)	dB	27.3	26.0	25.0
Gain Flatness (max)	dB	±0.3	±0.7	±1.0
Reverse Isolation	dB	33		
Noise Figure (max)	dB	2.0	2.5	3.0
Power Output @ 1 dB comp. (min)	dBm	16.0	14.5	14.0
IP3	dBm	+28		
IP2	dBm	+33		
Second Order Harmonic IP	dBm	+39		
VSWR Input / Output (max)		1.5:1 / 1.8:1	1.8:1 / 2.1:1	2.0:1 / 2.3:1
DC Current @ 15 Volts (max)	mA	30	32	34

Absolute Maximum Ratings

Parameter	Absolute Maximum			
Storage Temperature	-62°C to +125°C			
Case Temperature	125°C			
DC Voltage	+17 V			
Continuous Input Power	+10 dBm			
Short Term Input power (1 minute max.)	50 mW			
Peak Power (3 µsec max.)	0.5 W			
"S" Series Burn-In Temperature (case)	125°C			

Thermal Data: $V_{CC} = +15 V_{DC}$

Parameter	Rating
Thermal Resistance θ_{jc}	184°C/W
Transistor Power Dissipation Pd	0.155 W
Junction Temperature Rise Above Case T _{jc}	28°C

^{*} Over temperature performance limits for part number MAAM-007844-0CA801, guaranteed from 0°C to +50°C

Commitment to produce in volume is not guaranteed.

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ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.

PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

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 Visit www.macomtech.com for additional data sheets and product information.



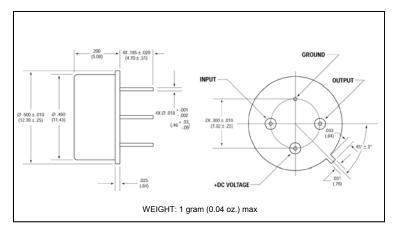
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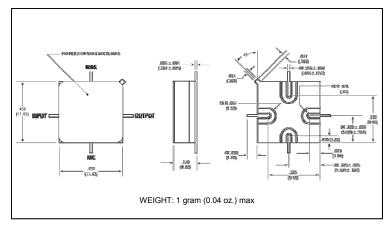
Typical Performance Curves at +25℃

Gain 100 150 200 250 300 350 Frequency (MHz) Noise Figure 15 V 100 150 200 250 300 350 400 450 ncy (MHz) Power Output (1 dB Gain Compression) Power Output (eBm) 160 200 Frequency (MHz) Intercept Point nierosot Point (dBm) 50 150 200 VSWR 50 100 150 200 250 300 350 400 450 Frequency (MHz)

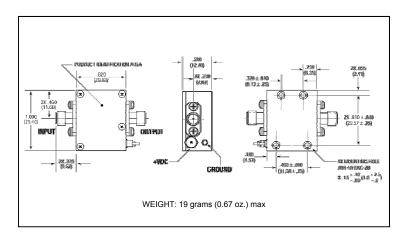
Outline Drawing: TO-8 *



Outline Drawing: Surface Mount



Outline Drawing: SMA Connectorized *



- * Dimensions are inches (millimeters) ±0.015 (0.38) unless otherwise specified.
 - India Tel: +91.80.4155721 Visit www.macomtech.com for additional data sheets and product information.